

		IO	A	6.0
	Without heatsink T _a =25			2.0
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, T _j =25		IFSM	A	150
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, T _j =25				300
Current squared time @1ms t 8.3ms T _j =25 , Rating of per diode		I ² t	A ² s	93.4
Storage temperature		T _{stg}		-55 ~ +150
Junction temperature		T _j		-55 ~ +150
Dielectric strength @ Terminals to case, AC 1 minute		V _{dis}	KV	2
Mounting torque @Recommend torque 5kg cm		Tor	kg cm	8

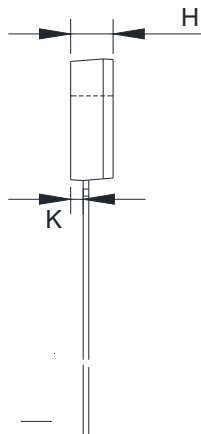


RD6JC80 THRU RD6JC100

Electrical Characteristics $T_a=25$



Outline Dimensions



JC		
Dim	Min	Max
A	19.60	20.40
B	11.50	12.30
C	10.10	10.90
D	1.00	1.30
E	14.20	15.00
F	4.88	5.28
H	3.10	3.70
I	2.95	3.35
J	5.30	5.90
K	0.70	1.30
L	0.30	0.60
M	1.70	2.10



RD6JC80 THRU RD6JC100

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